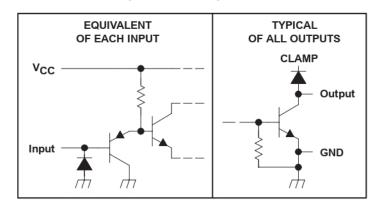
- Very Low Power Requirements
- Very Low Input Current
- Characterized for Use to 350 mA
- No Output Latch-Up at 50 V (After Conducting 300 mA)
- High-Voltage Outputs (70 V Min)
- Output Clamp Diodes for Transient Suppression (350 mA, 70 V)
- TTL- or MOS-Compatible Diode-Clamped Inputs
- Standard Supply Voltage
- Suitable for Hammer-Driver Applications

# description

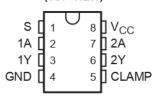
The SN75446 and SN75447 dual peripheral drivers are designed for use in systems that require high current, high voltage, and fast switching times. The SN75446 and SN75447 provide AND and NAND drivers, respectively. These devices have diode-clamped inputs as well as high-current, high-voltage inductive-clamp diodes on the outputs.

The SN75446 and SN75447 drivers are characterized for operation from 0°C to 70°C.

# schematics of inputs and outputs



### D OR P PACKAGE (TOP VIEW)



### **Function Tables**

### SN75446 (each AND driver)

INPU	INPUTS			
Α	S	Υ		
Н	Н	Н		
L	X	L		
Х	L	L		

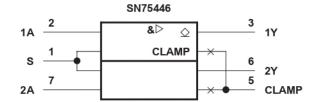
#### SN75447 (each NAND driver)

INPU	INPUTS		
Α	S	Υ	
Н	Н	L	
L	X	Н	
Х	L	Н	

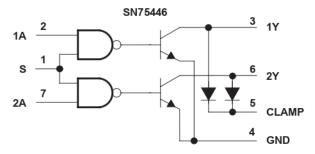
H = high level, L = low level

X = irrelevant

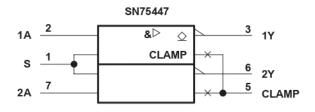
### logic symbols†

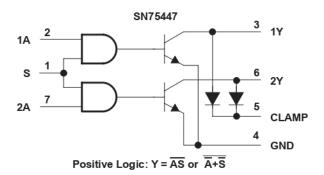


# logic diagrams (positive logic)



Positive Logic:  $Y = \overline{AS}$  or  $\overline{A+S}$ 





<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC publication 617-12.

# absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage, V <sub>CC</sub> (see Note 1)	7 V
Input voltage, V <sub>I</sub>	
Output current, IO (see Note 2)	400 mA
Output clamp-diode current	400 mA
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T <sub>A</sub>	0°C to 70°C
Storage temperature range, T <sub>stq</sub>	
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	

<sup>‡</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. Voltage values are with respect to network GND.
  - 2. Both halves of this dual circuit may conduct rated current simultaneously; however, power dissipation averaged over a short time interval must fall within the continuous dissipation ratings.

### DISSIPATION RATING TABLE

PACKAGE	T <sub>A</sub> ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T <sub>A</sub> = 25°C	T <sub>A</sub> = 70°C POWER RATING		
D	725 mW	5.8 mW/°C	464 mW		
Р	1000 mW	8.0 mW/°C	640 mW		



# recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V <sub>CC</sub>	4.75	5	5.25	V
High-level input voltage, V <sub>IH</sub>	2			V
Low-level input voltage, V <sub>IL</sub>			8.0	V
Operating free-air temperature range, TA	0		70	°C

# electrical characteristics over recommended operating free-air temperature range

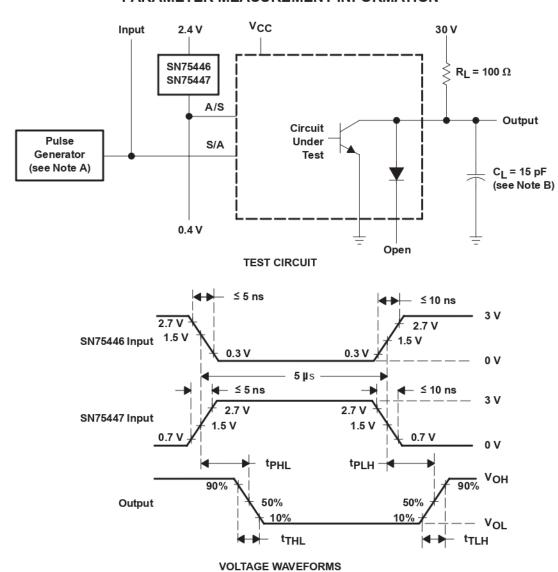
PARAMETER			TEST C	TEST CONDITIONS			MAX	UNIT
VIK	Input clamp voltage	I <sub>I</sub> = -12 mA	I <sub>I</sub> = -12 mA		-0.9	-1.5	V	
	Low-level output voltage			I <sub>OL</sub> = 100 mA		0.1	0.3	٧
\ <sub>\/-</sub> .			$V_{CC} = 4.75 \text{ V},$	I <sub>OL</sub> = 200 mA		0.22	0.45	
VOL			$V_{IH} = 2 V,$ $V_{II} = 0.8 V$	I <sub>OL</sub> = 300 mA		0.45	0.65	
			"	I <sub>OL</sub> = 350 mA		0.55	0.75	
V <sub>O(BR)</sub>	Output breakdown voltage		V <sub>CC</sub> = 4.75 V,	I <sub>OH</sub> = 100 <b>µ</b> A	70	100		V
V <sub>R(K)</sub>	Output clamp-diode reverse voltage		V <sub>CC</sub> = 4.75 V,	I <sub>R</sub> = 100 <b>µ</b> A	70	100		V
V <sub>F(K)</sub>	Output clamp-diode forward voltage		V <sub>CC</sub> = 4.75 V,	I <sub>F</sub> = 350 mA	0.6	1.2	1.6	V
ЮН	High-level output current		V <sub>CC</sub> = 4.75 V, V <sub>IL</sub> = 0.8 V,	V <sub>IH</sub> = 2 V, V <sub>OH</sub> = 70 V		1	100	μA
lН	High-level input current		V <sub>CC</sub> = 5.25 V,	V <sub>I</sub> = 5.25 V		0.01	10	μA
	Laurent annat	A input	V 5.25.V			-0.5	-10	
¹IL	Low-level input current	S input	$V_{CC} = 5.25 \text{ V},$	$V_{I} = 0.8 V$		-1	-20	μA
	Complete and a standard bind	SN75446	)/ F 2F )/	V <sub>I</sub> = 5 V		11	18	Δ
ICCH	Supply current, outputs high	SN75447	V <sub>CC</sub> = 5.25 V	V <sub>I</sub> = 0		11	18	mA
1	Correla correct contents less	SN75446	V 5 25 V	V <sub>I</sub> = 0		11	18	m A
ICCL	Supply current, outputs low	SN75447	- V <sub>CC</sub> = 5.25 V	V <sub>I</sub> = 5 V		11	18	mA

 $<sup>\</sup>dagger$  All typical values are at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C.

# switching characteristics, $V_{CC}$ = 5 V, $T_A$ = 25°C

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
t <sub>PLH</sub>	Propagation delay time, low-to-high-level output				300	750	ns
t <sub>PHL</sub>	Propagation delay time, high-to-low-level output	C <sub>L</sub> = 15 pF,	$R_L = 100 \Omega$		200	500	ns
tTLH	Transition time, low-to-high-level output	See Figure 1	_		50	100	ns
t <sub>THL</sub>	Transition time, high-to-low-level output				50	100	ns
VOH	High-level output voltage after switching	V <sub>S</sub> = 55 V, See Figure 2	$I_O \approx 300 \text{ mA},$	V <sub>S</sub> -0.018			٧

### PARAMETER MEASUREMENT INFORMATION

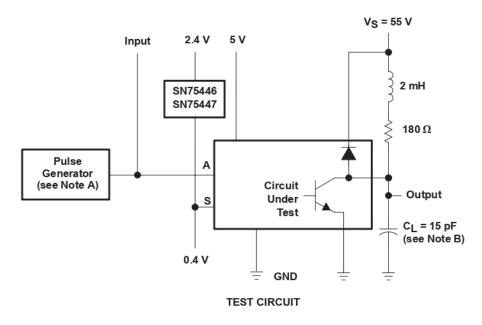


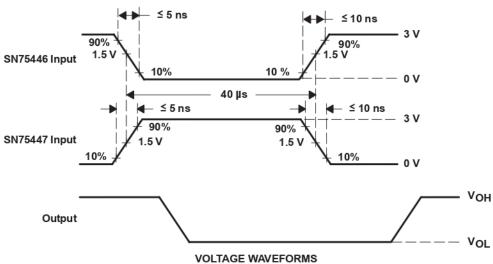
NOTES: A. The pulse generator has the following characteristics: PRR = 100 kHz,  $Z_O$  = 50  $\Omega$ 

B. C<sub>L</sub> includes probe and jig capacitance.

Figure 1. Test Circuit and Voltage Waveforms, Switching Characteristics

### PARAMETER MEASUREMENT INFORMATION





NOTES: A. The pulse generator has the following characteristics: PRR = 12.5 kHz,  $Z_O$  = 50  $\Omega$ .

B. C<sub>I</sub> includes probe and jig capacitance.

Figure 2. Latch-Up Test Circuit and Voltage Waveforms





ti.com 24-Jun-2005

#### PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
SN75446D	OBSOLETE	SOIC	D	8	TBD	Call TI	Call TI
SN75446DR	OBSOLETE	SOIC	D	8	TBD	Call TI	Call TI
SN75446P	OBSOLETE	PDIP	Р	8	TBD	Call TI	Call TI
SN75447D	OBSOLETE	SOIC	D	8	TBD	Call TI	Call TI
SN75447P	OBSOLETE	PDIP	Р	8	TBD	Call TI	Call TI

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (**RoHS**): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. – The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.